

Silicon NPN Power Transistors

2SC2437

**DESCRIPTION**

- With TO-3 package
- High voltage,high speed switching
- High reliability

**APPLICATIONS**

- Switching regulators
- DC-DC convertor
- Solid state relay
- General purpose power amplifiers

**PINNING(see Fig.2)**

PIN	DESCRIPTION
1	Base
2	Emitter
3	Collector

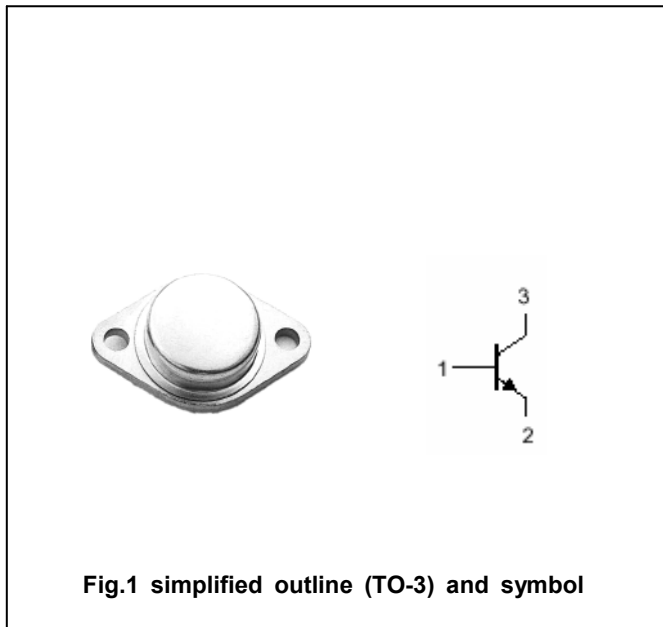


Fig.1 simplified outline (TO-3) and symbol

**Absolute maximum ratings(Ta=□)**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-base voltage	Open emitter	450	V
V <sub>CEO</sub>	Collector-emitter voltage	Open base	400	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	7	V
I <sub>C</sub>	Collector current		7	A
I <sub>B</sub>	Base current		2	A
P <sub>C</sub>	Collector power dissipation	T <sub>C</sub> =25□	100	W
T <sub>j</sub>	Junction temperature		150	□
T <sub>stg</sub>	Storage temperature		-55~150	□

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## CHARACTERISTICS

T<sub>j</sub>=25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =10mA ; I <sub>B</sub> =0	400			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =1mA ; I <sub>E</sub> =0	450			V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =0.1mA ; I <sub>C</sub> =0	7			V
V <sub>CEsat</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =7A ; I <sub>B</sub> =1.4A			1.5	V
V <sub>BEsat</sub>	Base-emitter saturation voltage	I <sub>C</sub> =7A ; I <sub>B</sub> =1.4A			1.2	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =450V ; I <sub>E</sub> =0			1.0	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =7V ; I <sub>C</sub> =0			0.1	mA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =3A ; V <sub>CE</sub> =4V	10			

## Switching times

t <sub>on</sub>	Turn-on time	I <sub>C</sub> =7A ; I <sub>B1</sub> =-I <sub>B2</sub> =1.4A R <sub>L</sub> =30Ω ; P <sub>W</sub> =20μs ; Duty≤2%			1.5	μs
t <sub>stg</sub>	Storage time				3.0	μs
t <sub>f</sub>	Fall time				1.5	μs

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PACKAGE OUTLINE



Fig.2 outline dimensions (unindicated tolerance:±0.1mm)